

Docket No.: 2336-255



PATENT

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :
Inventor(s): Seung Wan CHAE : Confirmation No.2799
U.S. Patent Application No. 10/812,015 : Group Art Unit: 2811
Filed: March 30, 2004 : Examiner: HUNG K VU

For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE
AND METHOD FOR MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed more than three months after the U.S. filing date and after the mailing date of the first Office Action on the merits, but before the mailing date of the Final Rejection or Notice of Allowance. For the Examiner's information, the references listed on the attached PTO/SB/08A were cited in closely related Application No.

10/811,808.

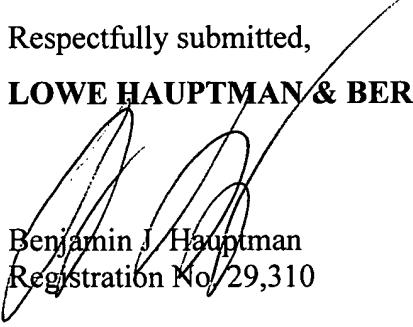
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A credit card authorization form in the amount of \$180.00 is attached. Any deficiency or overpayment should be charged or credited to Deposit Account No. 07-1337.

Respectfully submitted,
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Date: July 28, 2006

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.